

# 2SD1267, 2SD1267A

Silicon NPN triple diffusion planar type

For power amplification

Complementary to 2SB0942 (2SB942) and 2SB0942A (2SB942A)

## Features

- High forward current transfer ratio  $h_{FE}$  which has satisfactory linearity
- Low collector to emitter saturation voltage  $V_{CE(sat)}$
- Full-pack package which can be installed to the heat sink with one screw

## Absolute Maximum Ratings ( $T_C=25^\circ\text{C}$ )

Parameter	Symbol	Rated	Unit
Collector to base voltage	$V_{CBO}$	60	V
2SD1267A		80	
Collector to emitter voltage	$V_{CEO}$	60	V
2SD1267A		80	
Emitter to base voltage	$V_{EBO}$	5	V
Peak collector current	$I_{CP}$	8	A
Collector current	$I_C$	4	A
Collector power dissipation	$P_C$	40	W
$T_C=25^\circ\text{C}$		2	
Junction temperature	$T_j$	150	$^\circ\text{C}$
Storage temperature	$T_{stg}$	-55 to +150	$^\circ\text{C}$

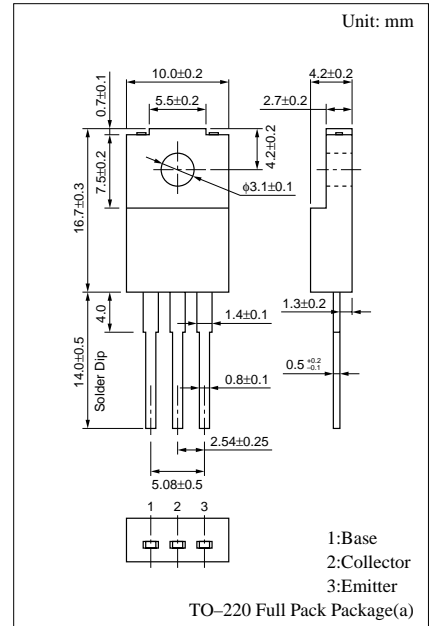
## Electrical Characteristics ( $T_C=25^\circ\text{C}$ )

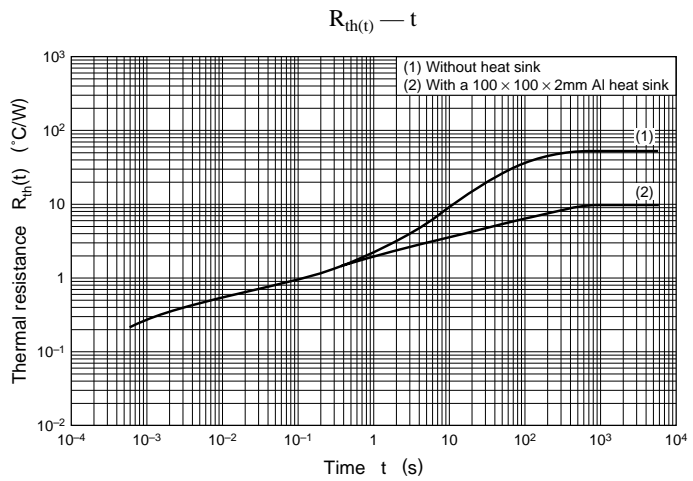
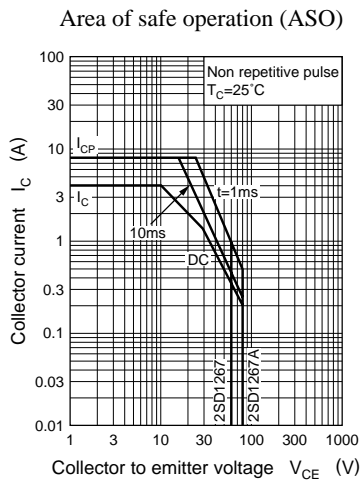
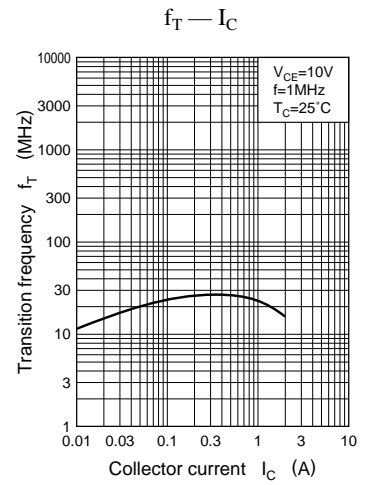
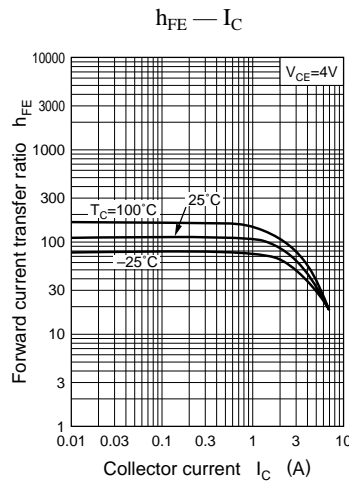
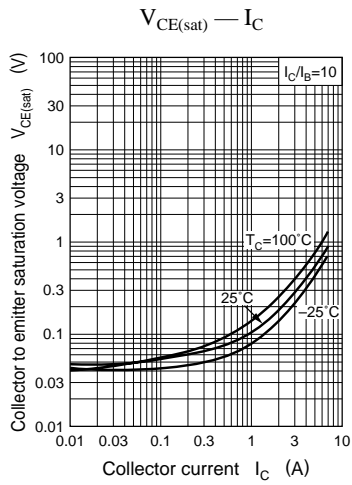
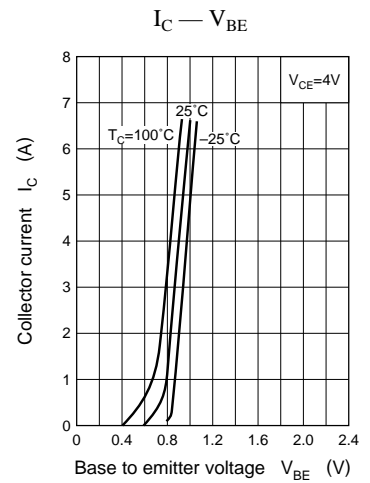
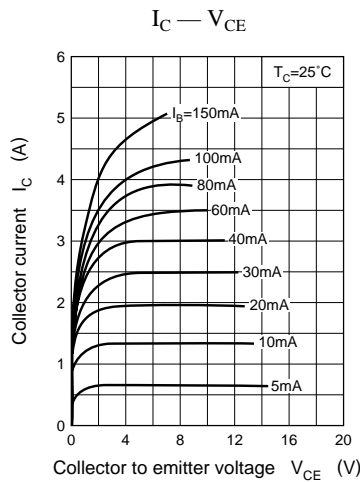
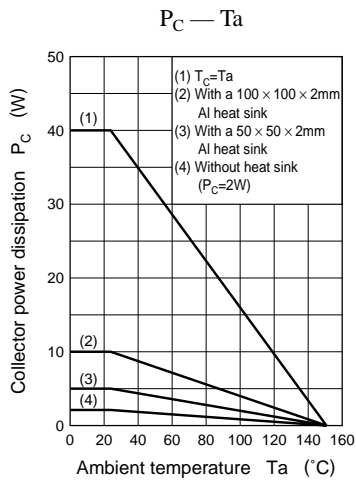
Parameter	Symbol	Conditions	min	typ	max	Unit	
Collector cutoff current	$I_{CES}$	$V_{CB} = 60\text{V}, V_{BE} = 0$			400	$\mu\text{A}$	
2SD1267A		$V_{CB} = 80\text{V}, V_{BE} = 0$			400		
Collector cutoff current	$I_{CEO}$	$V_{CE} = 30\text{V}, I_B = 0$			700	$\mu\text{A}$	
2SD1267A		$V_{CE} = 60\text{V}, I_B = 0$			700		
Emitter cutoff current	$I_{EBO}$	$V_{EB} = 5\text{V}, I_C = 0$			1	mA	
Collector to emitter voltage	$V_{CEO}$	$I_C = 30\text{mA}, I_B = 0$	60			V	
2SD1267A			80				
Forward current transfer ratio	$h_{FE1}^*$	$V_{CE} = 4\text{V}, I_C = 1\text{A}$	70		250		
	$h_{FE2}$	$V_{CE} = 4\text{V}, I_C = 3\text{A}$	15				
Base to emitter voltage	$V_{BE}$	$V_{CE} = 4\text{V}, I_C = 3\text{A}$			2	V	
Collector to emitter saturation voltage	$V_{CE(sat)}$	$I_C = 4\text{A}, I_B = 0.4\text{A}$			1.5	V	
Transition frequency	$f_T$	$V_{CE} = 5\text{V}, I_C = 0.5\text{A}, f = 1\text{MHz}$		20		MHz	
Turn-on time	$t_{on}$	$I_C = 4\text{A}, I_{B1} = 0.4\text{A}, I_{B2} = -0.4\text{A}, V_{CC} = 50\text{V}$		0.4		$\mu\text{s}$	
Storage time	$t_{stg}$				1.2		$\mu\text{s}$
Fall time	$t_f$				0.5		$\mu\text{s}$

\* $h_{FE1}$  Rank classification

Rank	Q	P
$h_{FE1}$	70 to 150	120 to 250

Note) The part numbers in the parenthesis show conventional part number.





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